

3.0Amp Fast Recovery Surface Mounted Rectifiers

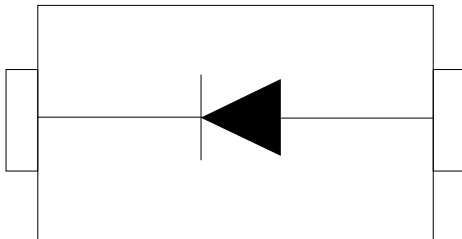
Description

General Application Standard Surface Mounted rectifier, encapsulated in a SMB Surface-Mounted Device (SMD) plastic package.

Features

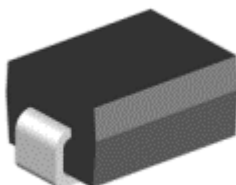
- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- Idea for printed circuit board
- Glass passivated junction chip
- Low reverse leakage
- High forward surge current capability
- High temperature soldering guaranteed 260℃/10 seconds at terminals

Dimensions and Pin Configuration



Graphic symbol

Package



SMB (Top View)

Mechanical Characteristics

- Case: JEDEC DO-214AA molded plastic
- Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity: Polarity symbol marking on body
- Case Material: “Green” Molding Compound

Applications

- For use in high frequency rectification of power Supplies, inverters, converters, and freewheeling Diodes for consumer and telecommunication

Ordering Informatio

Part Number	Shipping	Reel Size
RS3AB	3000/Tape & Reel	13 inch
RS3BB	3000/Tape & Reel	13 inch
RS3DB	3000/Tape & Reel	13 inch
RS3GB	3000/Tape & Reel	13 inch
RS3JB	3000/Tape & Reel	13 inch
RS3KB	3000/Tape & Reel	13 inch
RS3MB	3000/Tape & Reel	13 inch

Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%

Items	Symbol	RS3AB	RS3BB	RS3DB	RS3GB	RS3JB	RS3KB	RS3MB	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at $T_L=100^{\circ}\text{C}$	$I_{(AV)}$	3.0							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	I_{FSM}	100.0							A
Typical thermal resistance	R_{QJA}	60.0							$^{\circ}\text{C}/\text{W}$
Operating junction temperature range	T_J	$-55 \sim +150$							$^{\circ}\text{C}$
Storage temperature range	T_{STG}	$-55 \sim +150$							$^{\circ}\text{C}$

Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Items	Test conditions	Symbol	RS3AB	RS3BB	RS3DB	RS3GB	RS3JB	RS3KB	RS3MB	UNIT
Maximum instantaneous forward voltage	I _F =3.0A	V _F	1.3							V
Maximum DC reverse current	T _A =25℃	I _R	2							uA
at rated DC blocking voltage	T _A =125℃		200							
Maxinum reverse recovery time(Note 1)		T _{rr}	150				250	500		ns
Typical junction capacitance(Note 2)		C _j	60							pF

Note:

- Reverse recovery time test condition: $I_F=0.5\text{A}$ $I_R=1.0\text{A}$ $I_{rr}=0.25\text{A}$
- Measured at 1MHz and applied reverse voltage of 4.0V D.C.

Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)

FIG.1-DERATING CURVE OUTPUT RECTIFIED CURRENT

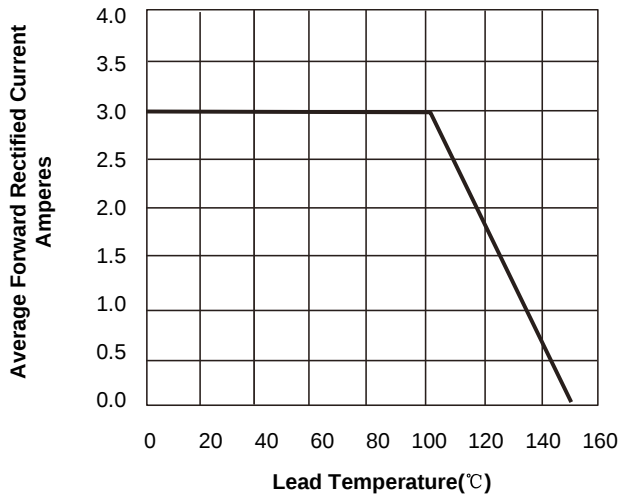


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD

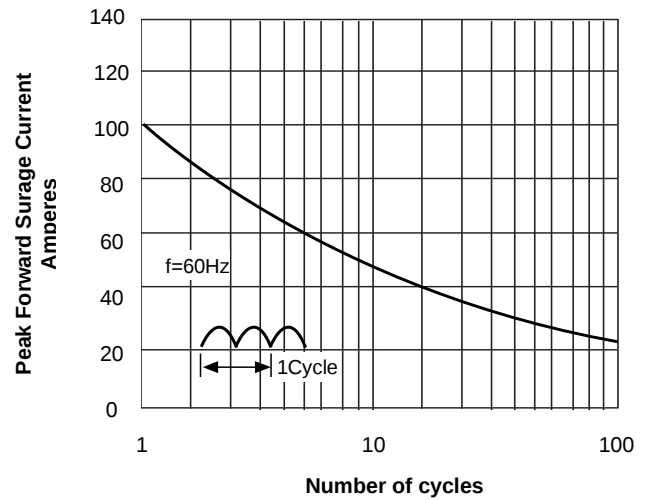


FIG.3-TYPICAL FORWARD VOLTAGE CHARACTERISTICS

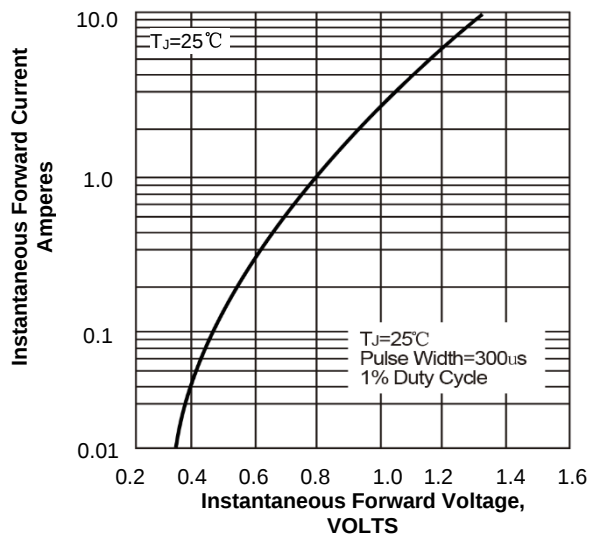
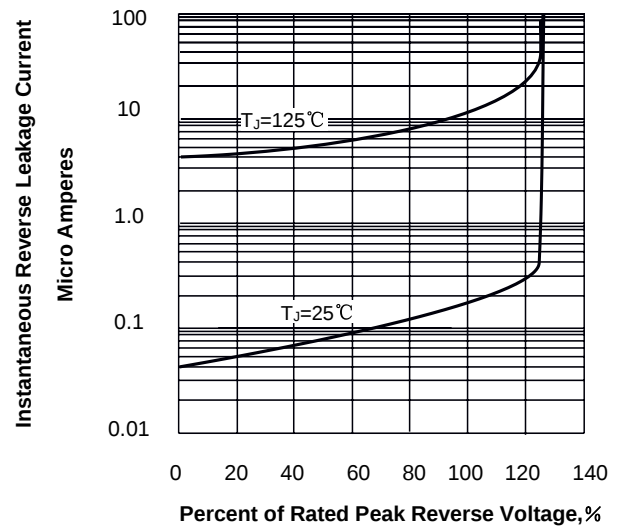
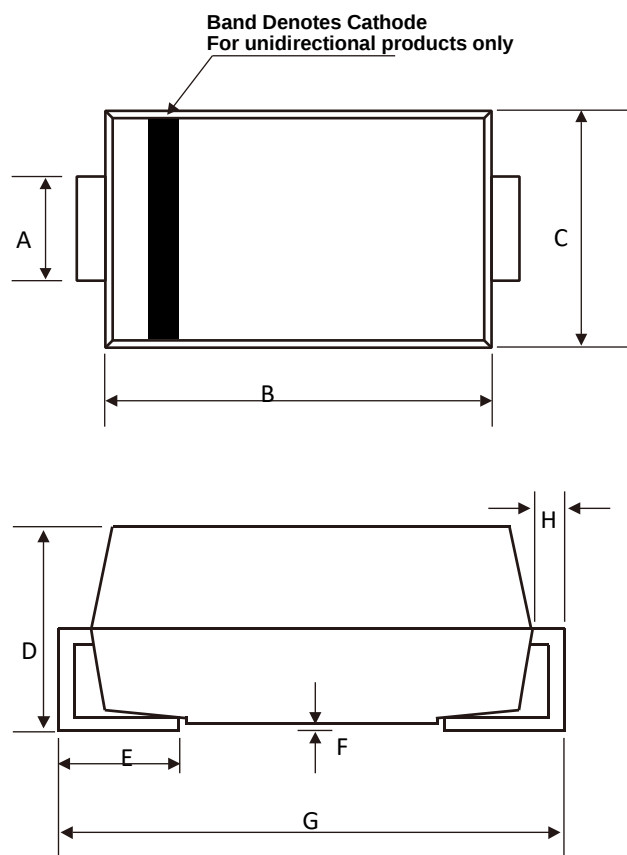


FIG.4-TYPICAL REVERSE LEAKAGE CHARACTERISTICS

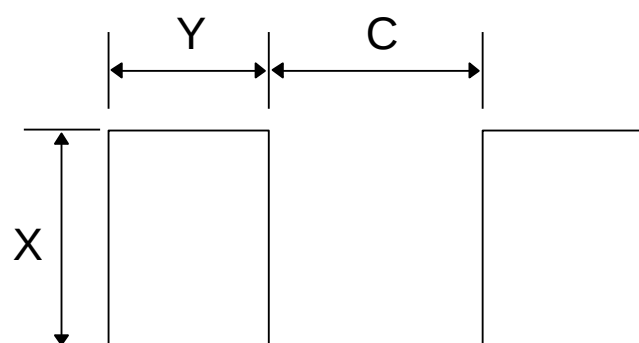


SMB Package Outline Drawing



Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	1.80	2.20	0.071	0.087
B	4.06	4.57	0.160	0.180
C	3.30	3.94	0.130	0.155
D	2.13	2.44	0.084	0.096
E	0.76	1.52	0.030	0.060
F	----	0.203	----	0.008
G	5.08	5.59	0.205	0.220
H	0.152	0.305	0.006	0.012

Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
X	2.30	0.091
Y	2.00	0.078
C	2.10	0.083

IMPORTANT NOTICE

The information given in this document is believed to be accurate and reliable but shall in no event be regarded as a guarantee of conditions or characteristics. PN-Silicon assumes no responsibility for any errors in this document, or for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of PN-Silicon.

The product listed in this document are designed to be used with ordinary electronic equipment or devices and are not authorized to used with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, aerospace machinery, nuclear-reactor controllers, automotive and other safety device.)

The  logo is a registered trademark of PN-Silicon co., ltd which reserves the right to make changes to the product or this document at any time without notice. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. PN-Silicon makes no warranty, representation or guarantee, express or implied, regarding the suitability of its products for any particular purpose. All rights reserved.